

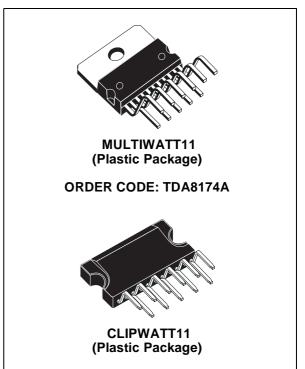
### VERTICAL DEFLECTION CIRCUIT

- Ramp Generator
- Independent Amplitude Adjustement
- Buffer Stage
- Power Amplifier
- Flyback Generator
- Thermal Protection
- Internal Reference Voltage Decoupling

#### DESCRIPTION

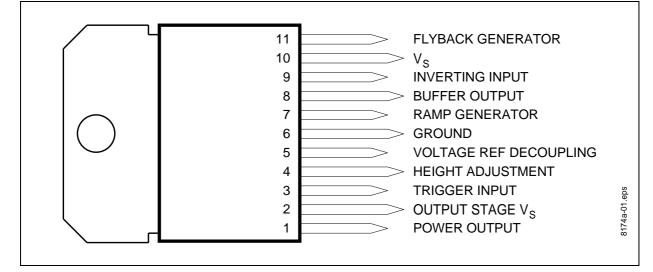
TDA8174A and TDA8174AW are monolithic integrated circuits.

It is a full performance and very efficient vertical deflection circuit intended for direct drive of a TV picture tube in Color and B & W television as well as in Monitor and Data displays.

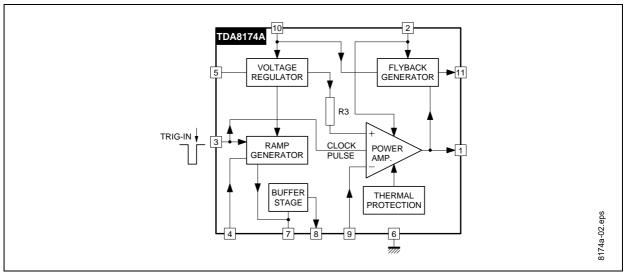


ORDER CODE: TDA8174AW

**Figure 1. Pin Connections** 



### Figure 2. Block Diagram



### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>S</sub>	Supply Voltage	35	V
V <sub>1</sub> , V <sub>2</sub>	Flyback Peak Voltage	65	V
V <sub>3</sub>	Trigger Input Voltage	20	V
V <sub>9</sub>	Amplifier Input Voltage	GND, V <sub>S</sub>	V
I <sub>0</sub>	Output Peak-to-peak Current (non repetitive t = 2ms)	6	A
I <sub>0</sub>	Output Peak-to-peak Current t > 10µs	4	A
I <sub>11</sub>	Pin 11 DC Current at V <sub>1</sub> < V <sub>10</sub>	100	mA
I <sub>11</sub>	Pin 11 Peak-to-peak Current @ t <sub>fly</sub> < 1.5ms	3	A
P <sub>tot</sub>	Total Power Dissipation @ T <sub>tab</sub> = 60°C	30	W
T <sub>stg</sub>	Storage Temperature	- 40, +150	°C
Ti	Junction Temperature	0, +150	°C
T <sub>amb</sub>	Ambient Temperature	0, +70	°C

### THERMAL DATA

Symbol	Parameter		Value	Unit	
R <sub>th</sub> (j-tab)	Thermal Resistance Junction-tab	Max.	3	°C/W	
R <sub>th</sub> (j-a)	Thermal Resistance Junction-ambient	Max.	40	°C/W	

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
l <sub>2</sub>	Pin 2 Quiescent Current	$I_1 = 0, I_{11} = 0$		16	36	mA
I <sub>10</sub>	Pin 10 Quiescent Current	$I_1 = 0, I_{11} = 0$		15	30	mA
-l <sub>7</sub>	Ramp Generator Bias Current	V <sub>7</sub> = 0			0.5	μA
-l <sub>7</sub>	Ramp Generator Current	$V_7 = 0, -I_4 = 20\mu A$	18.5	20	21.5	μA
dl <sub>7</sub> /l <sub>7</sub>	Ramp Generator Linearity	$V_6 = 0$ to 15V, $-I_4 = 20\mu A$		0.2	1	%
V	Quiescent Output Voltage	$R_a = 30k\Omega, R_b = 10k\Omega, V_s = 35V$	17.0	17.8	18.6	V
V <sub>1</sub>		$R_a = 6.8 k\Omega$ , $R_b = 10 k\Omega$ , $V_s = 15 V$	7.2	7.5	7.8	V
V	Out Saturation Voltage to GND	I <sub>1</sub> = 0.5A		0.5	1	V
$V_{1L}$		I <sub>1</sub> = 1.2A		1	1.4	V
M	Out Saturation Voltage to $V_s$	-I <sub>1</sub> = 0.5A		1.1	1.6	V
$V_{1H}$		-I <sub>1</sub> = 1.2A		1.6	2.2	V
V <sub>4</sub>	Reference Voltage	-I <sub>4</sub> = 20μΑ	6.3	6.6	6.9	V
dV <sub>4</sub> /V <sub>s</sub>	Reference Voltage Drift Versus Vs	V <sub>s</sub> = 10V to 35V		1	2	mV/V
dV <sub>4</sub> /d <sub>l4</sub>	Reference Voltage Drift Versus I <sub>4</sub>	I <sub>4</sub> = 10μA to 30μA		1.5	2	mV/µA
V <sub>5</sub>	Internal Reference Voltage		4.25	4.45	4.65	V
V <sub>D11</sub> -10	Diode Fwd Voltage	I <sub>D</sub> = 1.2A		2.2	3	V
V <sub>D1</sub> -2	Diode Fwd Voltage	I <sub>D</sub> = 1.2A		2.2	3	V
GV	Output Stage Open Loop Gain	f = 100Hz		60		dB
V <sub>fs</sub>	V <sub>10</sub> -11 Saturation Voltage	-I <sub>11</sub> = 1.2A		1.5	2.5	V
V <sub>11</sub>	Pin 11 Scanning Voltage	I <sub>11</sub> = 20mA		1.7	3	V
V <sub>3</sub>	Trigger Input Threshold	(see note 1)	2.6	3.0	3.4	V
l <sub>3</sub>	Trigger Input Bias Current	V <sub>IN</sub> = V <sub>3</sub> - 0.2V			30	μA
t <sub>3</sub>	Trigger Input Width	(see note 2)	20	60	Th	μS

### **DC ELECTRICAL CHARACTERISTICS** ( $V_0 = 35V \cdot T_{emb} = 25^{\circ C}$ unless otherwise specified)

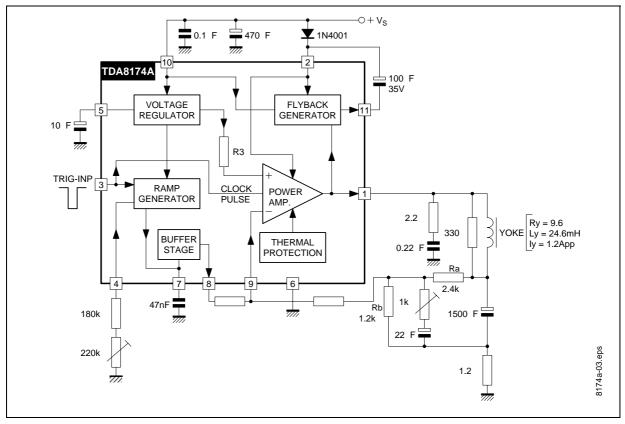
**Notes:** 1. The trigger input circuit can accept, with a metal option, positive and negative going input pulses. 2. Th =  $\frac{1.2 \cdot T_S}{V_{PP}}$  where: T<sub>S</sub> is the vertical period and V<sub>PP</sub> is ramp amplitude at Pin7.

## AC ELECTRICAL CHARACTERISTICS ( $V_S = 24V$ ; $T_{amb} = 25^{oC}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vs	Operating Supply Voltage Range		10		30	V
I <sub>1</sub>	Peak-to-peak Operating Current Range		0.4			А
ا <sub>s</sub>	Supply Current	$I_y = 2.4A_{pp}$		315		mA
V <sub>1</sub>	Flyback Voltage	$I_y = 2.4A_{pp}$		51		V
V <sub>8</sub>	Sawtooth Pedestall Voltage			1.85		V
T <sub>js</sub>	Junction Temp. for Thermal Shutdown			145		°C

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### Figure 3. Application Circuit

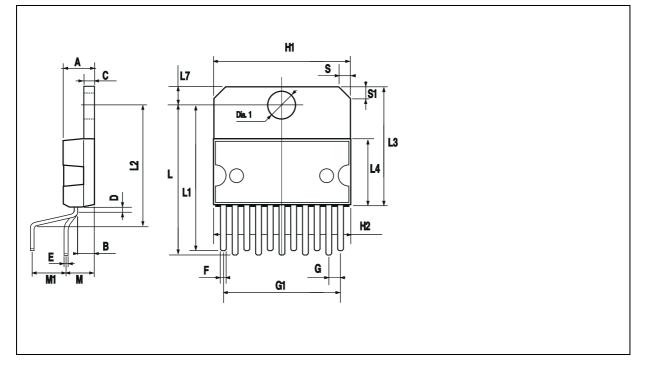


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### PACKAGE MECHANICAL DATA

11 PINS - PLASTIC MULTIWATT

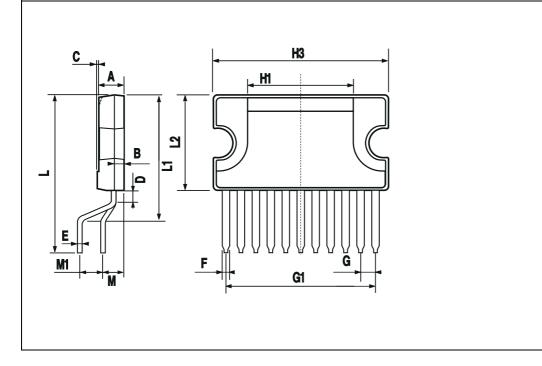
### Figure 4. 11-Pin Package



PACKAGE MECHANICAL DATA (Cont'd)

11 PINS - PLASTIC CLIPWATT

### Figure 5. 11-Pin Package



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